# NSN 5961-01-079-8391

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#### Inclosure Material:

Metal

### **Overall Length:**

Between 0.250 inches and 0.350 inches

## **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage, dc and 80.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, dc

#### **Current Rating Per Characteristic:**

Between 6.00 amperes source cutoff current and 30.00 amperes source cutoff current

## Power Rating Per Characteristic:

250.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### Test Data Document:

04971-109217 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

1 case and 2 pin

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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